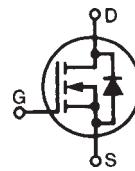
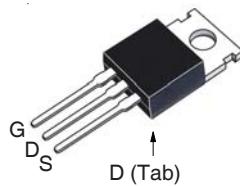


**X4-Class  
Power MOSFET™**
**AEC Q101 Qualified**
**N-Channel Enhancement Mode  
Avalanche Rated**
**IXTP150N15X4A**

 $V_{DSS} = 150V$   
 $I_{D25} = 150A$   
 $R_{DS(on)} \leq 7.2m\Omega$ 
**TO-220  
(IXTP)**

G = Gate      D = Drain  
S = Source      Tab = Drain

| Symbol        | Test Conditions  | Maximum Ratings |            |
|---------------|--|-----------------|------------|
| $V_{DSS}$     | $T_J = 25^\circ C$ to $175^\circ C$                                | 150             | V          |
| $V_{DGR}$     | $T_J = 25^\circ C$ to $175^\circ C$ , $R_{GS} = 1M\Omega$          | 150             | V          |
| $V_{GSS}$     | Continuous   | $\pm 20$        | V          |
| $V_{GSM}$     | Transient  | $\pm 30$        | V          |
| $I_{D25}$     | $T_c = 25^\circ C$   | 150             | A          |
| $I_{DM}$      | $T_c = 25^\circ C$ , Pulse Width Limited by $T_{JM}$               | 260             | A          |
| $I_A$         | $T_c = 25^\circ C$   | 75              | A          |
| $E_{AS}$      | $T_c = 25^\circ C$   | 1               | J          |
| $dv/dt$       | $I_s \leq I_{DM}$ , $V_{DD} \leq V_{DSS}$ , $T_J \leq 150^\circ C$ | 10              | V/ns       |
| $P_D$         | $T_c = 25^\circ C$   | 480             | W          |
| $T_J$         |  | -55 ... +175    | $^\circ C$ |
| $T_{JM}$      |  | 175             | $^\circ C$ |
| $T_{stg}$     |  | -55 ... +175    | $^\circ C$ |
| $T_L$         | Maximum Lead Temperature for Soldering                             | 300             | $^\circ C$ |
| $T_{SOLD}$    | 1.6 mm (0.062in.) from Case for 10s                                | 260             | $^\circ C$ |
| $M_d$         | Mounting Torque  | 1.13 / 10       | Nm/lb.in   |
| <b>Weight</b> |  | 3               | g          |

**Features**

- International Standard Package
- Low  $R_{DS(ON)}$  and  $Q_G$
- Avalanche Rated
- Low Package Inductance

**Advantages**

- High Power Density
- Easy to Mount
- Space Savings

**Applications**

- Switch-Mode and Resonant-Mode Power Supplies
- DC-DC Converters
- PFC Circuits
- AC and DC Motor Drives
- Robotics and Servo Controls

| Symbol       | Test Conditions<br>( $T_J = 25^\circ C$ , Unless Otherwise Specified) | Characteristic Values |      |                           |
|--------------|---|-----------------------|------|---------------------------|
|              |   | Min.                  | Typ. | Max.                      |
| $BV_{DSS}$   | $V_{GS} = 0V$ , $I_D = 250\mu A$                                      | 150                   |      | V                         |
| $V_{GS(th)}$ | $V_{DS} = V_{GS}$ , $I_D = 250\mu A$                                  | 2.5                   |      | 4.5 V                     |
| $I_{GSS}$    | $V_{GS} = \pm 20V$ , $V_{DS} = 0V$                                    |                       |      | $\pm 100$ nA              |
| $I_{DSS}$    | $V_{DS} = V_{DSS}$ , $V_{GS} = 0V$<br>$T_J = 150^\circ C$             |                       |      | 10 $\mu A$<br>500 $\mu A$ |
| $R_{DS(on)}$ | $V_{GS} = 10V$ , $I_D = 0.5 \cdot I_{D25}$ , Note 1                   | 6.2                   | 7.2  | $m\Omega$                 |

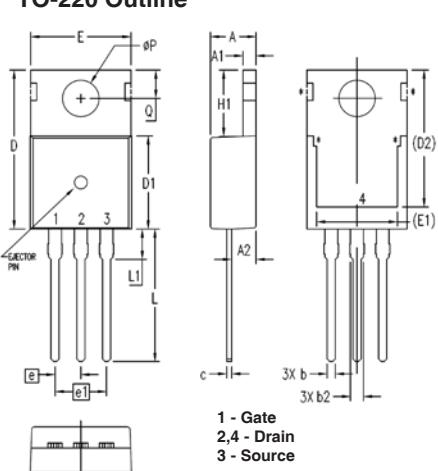
| Symbol                              | Test Conditions<br>( $T_J = 25^\circ\text{C}$ , Unless Otherwise Specified)                                    | Characteristic Values |      |                           |
|-------------------------------------|--|-----------------------|------|---------------------------|
|                                     |  | Min.                  | Typ. | Max                       |
| $g_{fs}$                            | $V_{DS} = 10\text{V}$ , $I_D = 60\text{A}$ , Note 1  | 70                    | 120  | S                         |
| $R_{GI}$                            | Gate Input Resistance  |                       | 1.3  | $\Omega$                  |
| $C_{iss}$                           | $V_{GS} = 0\text{V}$ , $V_{DS} = 25\text{V}$ , $f = 1\text{MHz}$   | 5500                  |      | pF                        |
| $C_{oss}$                           |  | 900                   |      | pF                        |
| $C_{rss}$                           |  | 4                     |      | pF                        |
| <b>Effective Output Capacitance</b> |  |                       |      |                           |
| $C_{o(er)}$                         | Energy related } $V_{GS} = 0\text{V}$  | 660                   |      | pF                        |
| $C_{o(tr)}$                         | Time related } $V_{DS} = 0.8 \cdot V_{DSS}$  | 2100                  |      | pF                        |
| $t_{d(on)}$                         | $V_{GS} = 10\text{V}$ , $V_{DS} = 0.5 \cdot V_{DSS}$ , $I_D = 0.5 \cdot I_{D25}$<br>$R_G = 2\Omega$ (External) | 23                    |      | ns                        |
| $t_r$                               |  | 5                     |      | ns                        |
| $t_{d(off)}$                        |  | 60                    |      | ns                        |
| $t_f$                               |  | 6                     |      | ns                        |
| $Q_{g(on)}$                         | $V_{GS} = 10\text{V}$ , $V_{DS} = 0.5 \cdot V_{DSS}$ , $I_D = 0.5 \cdot I_{D25}$                               | 105                   |      | nC                        |
| $Q_{gs}$                            |  | 30                    |      | nC                        |
| $Q_{gd}$                            |  | 28                    |      | nC                        |
| $R_{thJC}$                          |  |                       | 0.31 | $^\circ\text{C}/\text{W}$ |
| $R_{thCS}$                          |  | 0.50                  |      | $^\circ\text{C}/\text{W}$ |

### Source-Drain Diode

| Symbol   | Test Conditions<br>( $T_J = 25^\circ\text{C}$ , Unless Otherwise Specified)   | Characteristic Values |      |     |
|----------|---|-----------------------|------|-----|
|          |   | Min.                  | Typ. | Max |
| $I_s$    | $V_{GS} = 0\text{V}$  |                       | 150  | A   |
| $I_{SM}$ | Repetitive, pulse Width Limited by $T_{JM}$                                   |                       | 600  | A   |
| $V_{SD}$ | $I_F = 100\text{A}$ , $V_{GS} = 0\text{V}$ , Note 1                           |                       | 1.4  | V   |
| $t_{rr}$ | $I_F = 75\text{A}$ , $-di/dt = 100\text{A}/\mu\text{s}$<br>$V_R = 75\text{V}$ | 100                   |      | ns  |
| $Q_{RM}$ |   | 350                   |      | nC  |
| $I_{RM}$ |   | 7                     |      | A   |

Note 1. Pulse test,  $t \leq 300\mu\text{s}$ , duty cycle,  $d \leq 2\%$ .

### TO-220 Outline



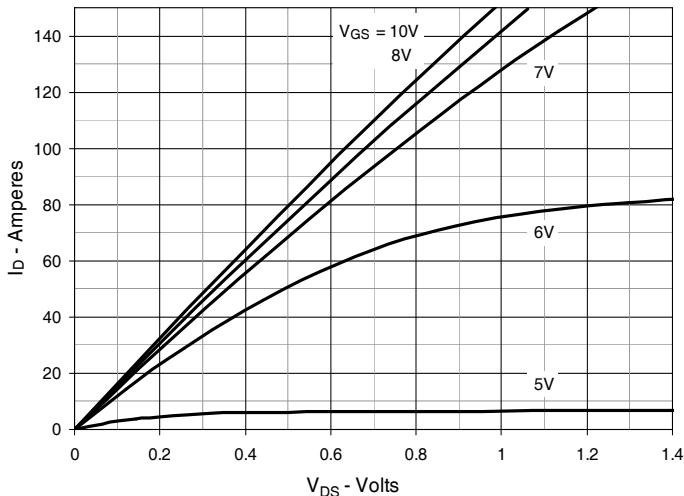
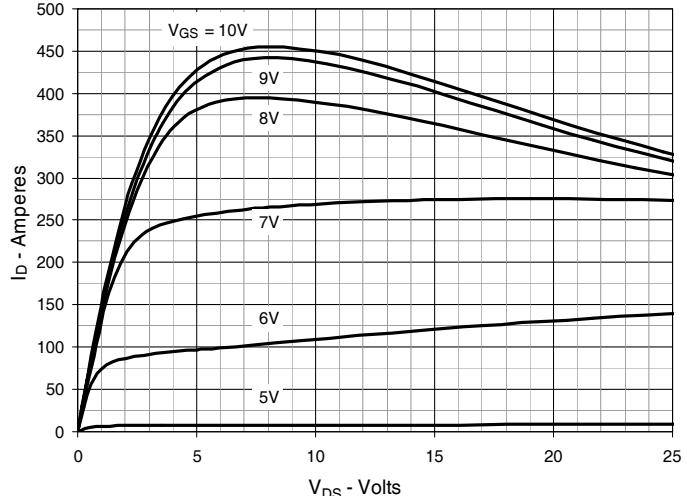
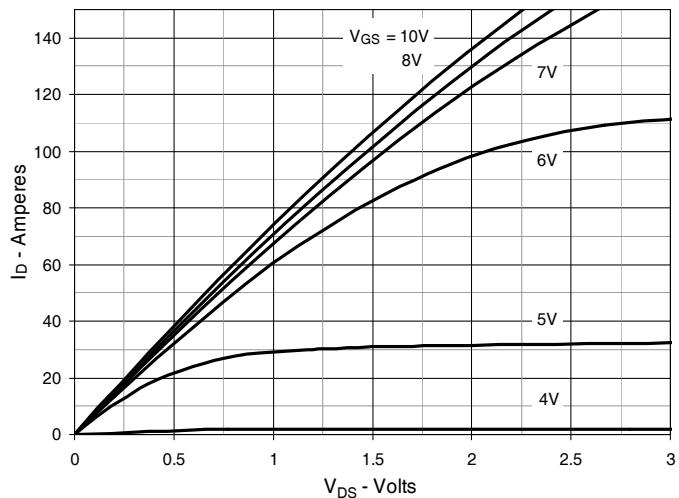
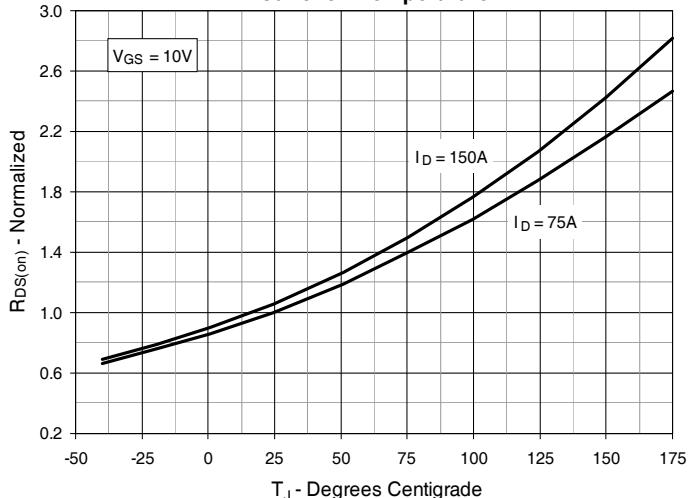
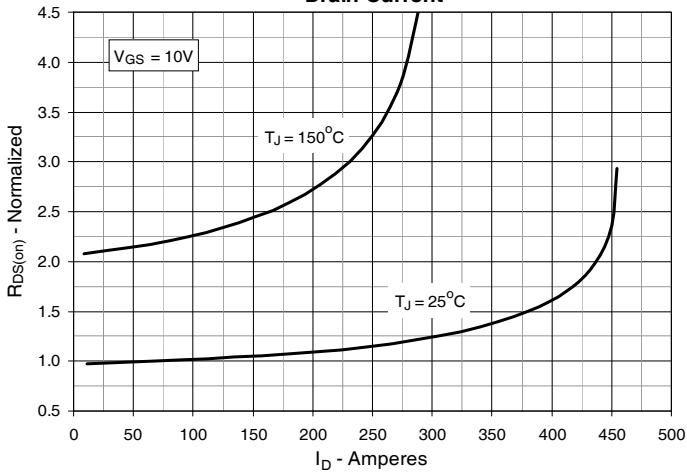
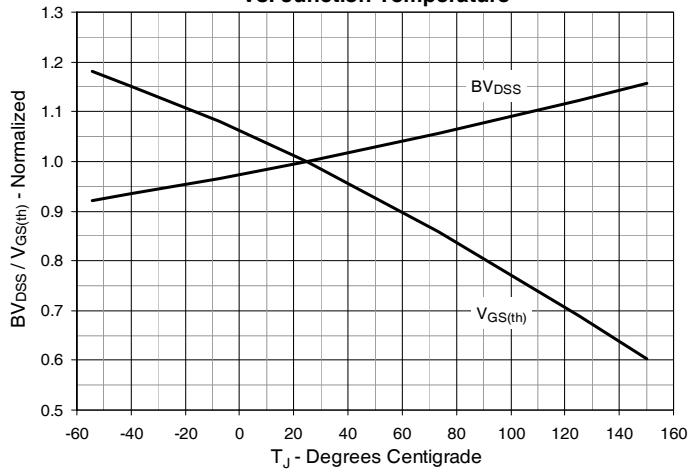
| SYM           | INCHES   |      | MILLIMETERS |       |
|---------------|----------|------|-------------|-------|
|               | MIN      | MAX  | MIN         | MAX   |
| A             | .169     | .185 | 4.30        | 4.70  |
| A1            | .047     | .055 | 1.20        | 1.40  |
| A2            | .079     | .106 | 2.00        | 2.70  |
| b             | .024     | .039 | 0.60        | 1.00  |
| b2            | .045     | .057 | 1.15        | 1.45  |
| c             | .014     | .026 | 0.35        | 0.65  |
| D             | .587     | .626 | 14.90       | 15.90 |
| D1            | .335     | .370 | 8.50        | 9.40  |
| (D2)          | .500     | .531 | 12.70       | 13.50 |
| E             | .382     | .406 | 9.70        | 10.30 |
| (E1)          | .283     | .323 | 7.20        | 8.20  |
| e             | .100 BSC |      | 2.54 BSC    |       |
| e1            | .200 BSC |      | 5.08 BSC    |       |
| H1            | .244     | .268 | 6.20        | 6.80  |
| L             | .492     | .547 | 12.50       | 13.90 |
| L1            | .110     | .154 | 2.80        | 3.90  |
| $\emptyset P$ | .134     | .150 | 3.40        | 3.80  |
| Q             | .106     | .126 | 2.70        | 3.20  |

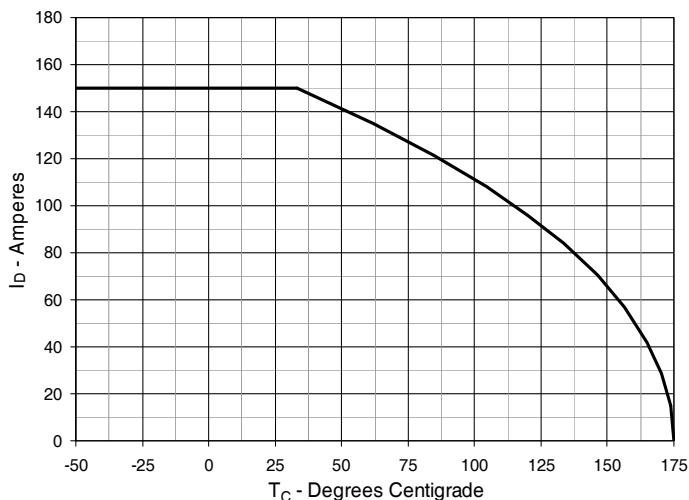
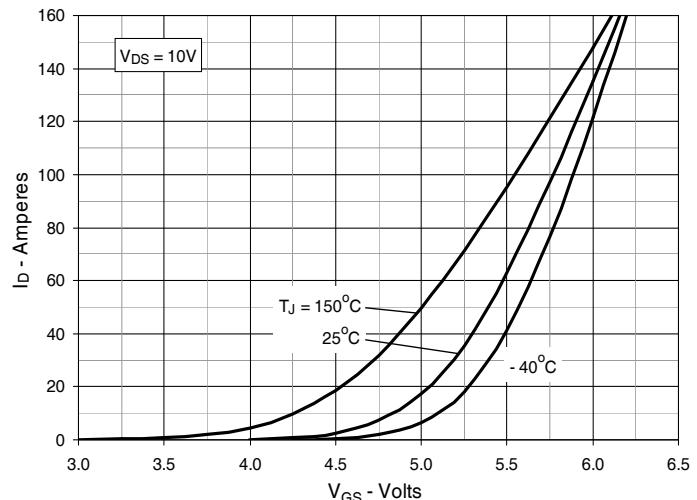
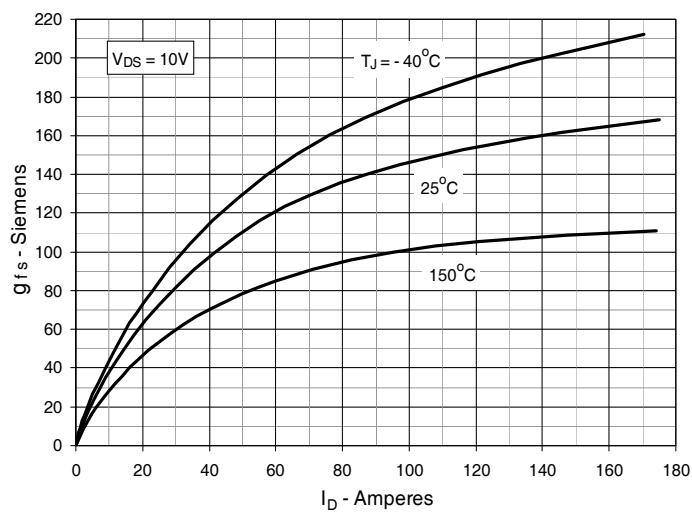
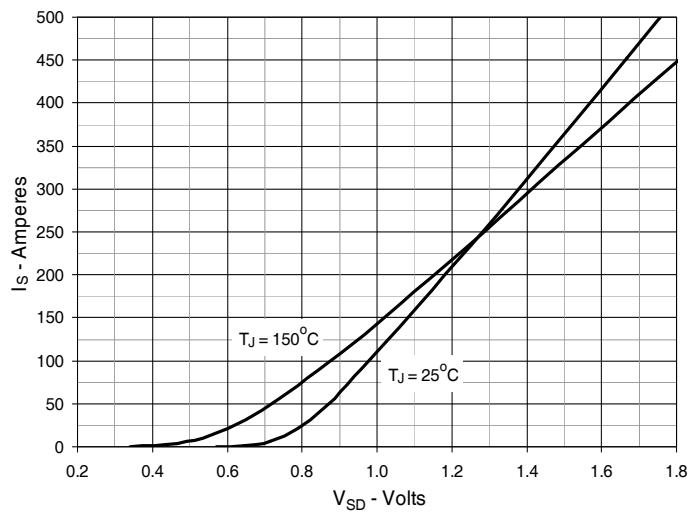
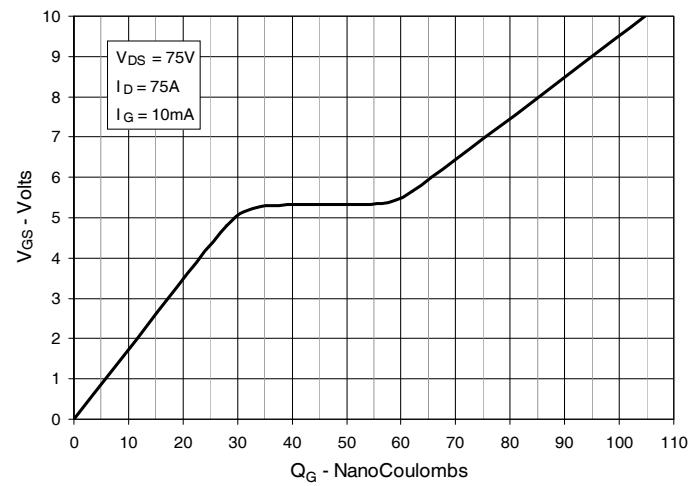
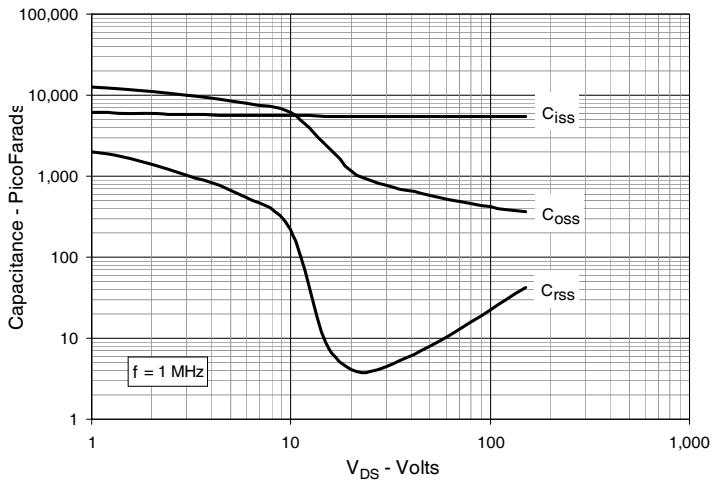
### ADVANCE TECHNICAL INFORMATION

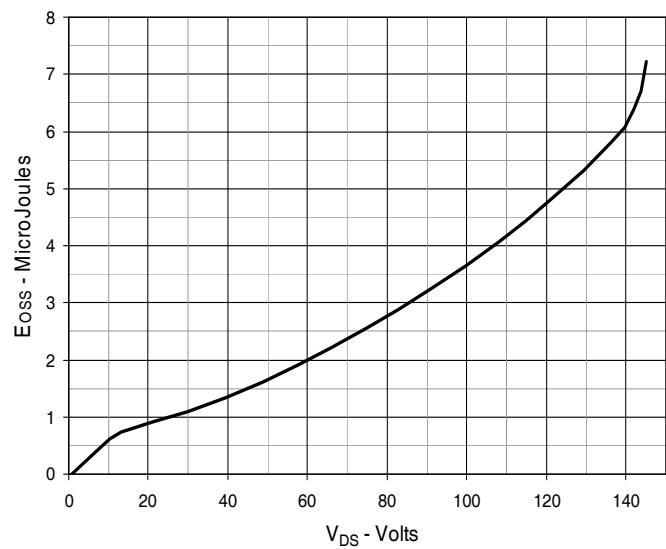
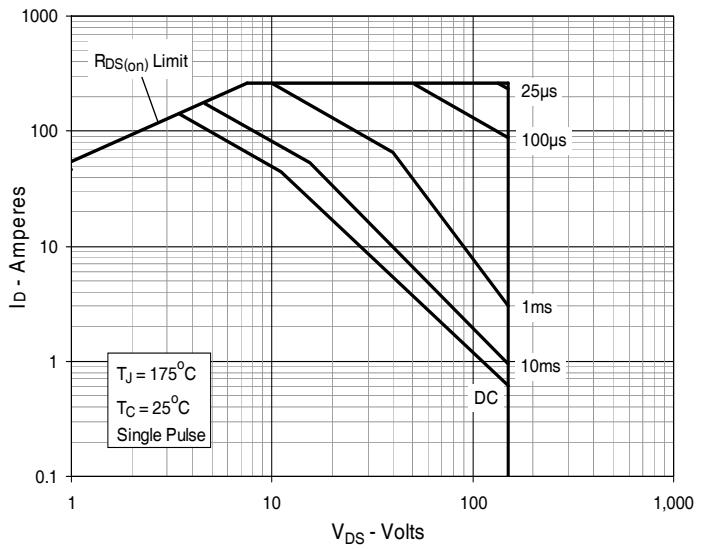
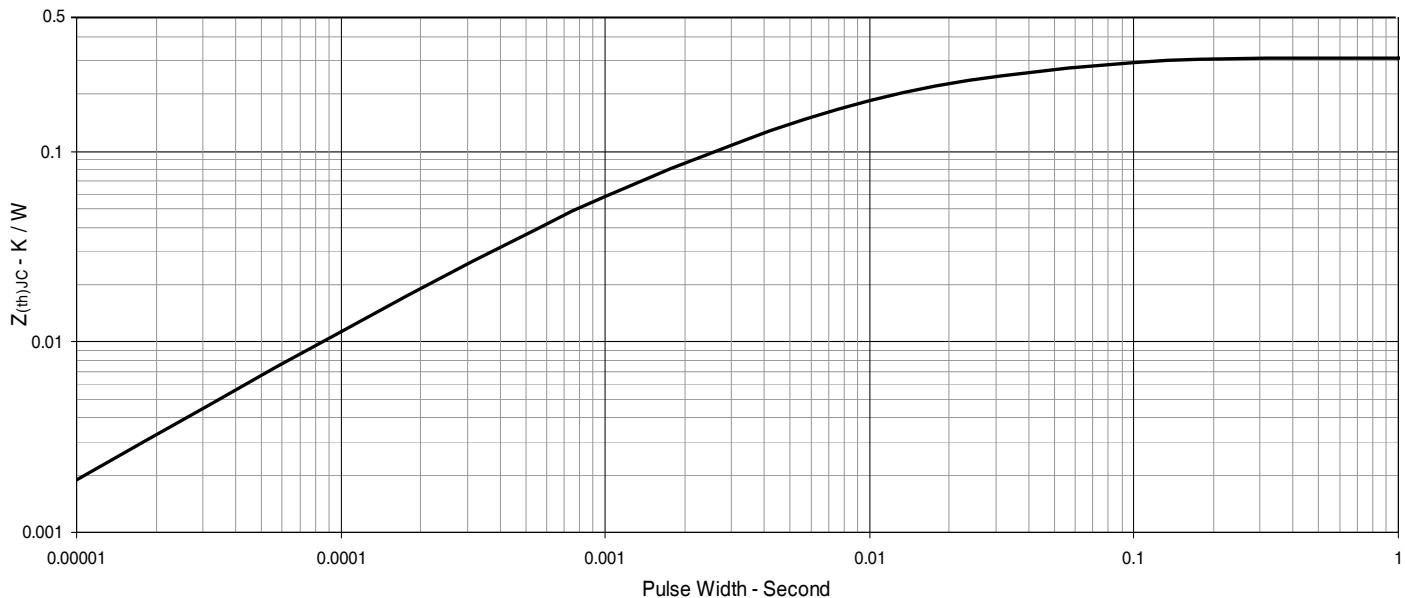
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**Fig. 1. Output Characteristics @  $T_J = 25^\circ\text{C}$** **Fig. 2. Extended Output Characteristics @  $T_J = 25^\circ\text{C}$** **Fig. 3. Output Characteristics @  $T_J = 150^\circ\text{C}$** **Fig. 4.  $R_{DS(on)}$  Normalized to  $I_D = 75\text{A}$  Value vs. Junction Temperature****Fig. 5.  $R_{DS(on)}$  Normalized to  $I_D = 75\text{A}$  Value vs. Drain Current****Fig. 6. Normalized Breakdown & Threshold Voltages vs. Junction Temperature**

**Fig. 7. Maximum Drain Current vs. Case Temperature****Fig. 8. Input Admittance****Fig. 9. Transconductance****Fig. 10. Forward Voltage Drop of Intrinsic Diode****Fig. 11. Gate Charge****Fig. 12. Capacitance**

**Fig. 13. Output Capacitance Stored Energy****Fig. 14. Forward-Bias Safe Operating Area****Fig. 15. Maximum Transient Thermal Impedance**



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